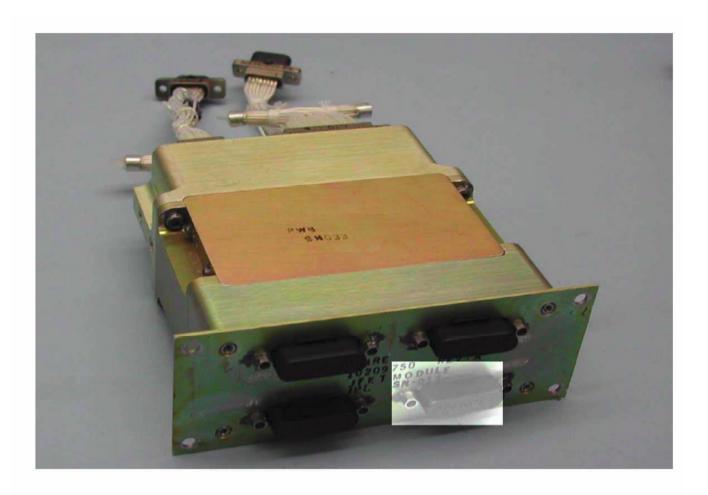
JPL Hardware Requirements Certification Review – SPIRE Element No. D-30474

JPL Hardware Requirements Certification Review - SPIRE Element No. D-30474

Assembly / Subsystem		PEM				Phone		Section		Date
SPIRE	SPIRE		Martin Herman			(818) 354-8	(818) 354-8541			3 February, 2005
Drawing/ Part No.	Dwg. Rev.	No	men	clat	ure	Serial No.	Model	Туре	Final IR No.	Mass (Meas. / Req.)
10209750-1	В	JF	ET N	lodu	ile	013	FLIGHT	N/A	923845	275.8 gm / 305 gm
Check applicable answer an explanation in remarks colu		Y E S	N O	N A	R	e m a r k s			Data Attachments	Signature & Date
Are all drawings and specific complete, approved, released		Х						14. Lates Attach	t Top Assembly drawings ed None	Cognizant Engineer Lew/Sey 2/18/05
Do the released drawings a specifications reflect all appro-		Χ						15. List of Attach	open ECRs ed 🔀 None	PEM 1/18/05
3. Is hardware identical to oth delivered? If no, provide diffe		х						16. Waive	rs (RFW request for waiver)	Sarrain Valore le
4. Does the hardware meet its requirements, specifications, v		Х			EIDP attached. Also see item # 8 attachments.		17. Open MRB ☐ Attached ☑ None		Environments/Reliability	
Are all IR and MRB disposiconcurred by QA?	itioned and	Х	*					18. Open I	PFR on this H/W ed ⊠ None	Mission Assurance Mgr.
6. Is complete as-built list info included in the build book?	ormation	Х						19. Open I	PFR on similar H/W ed 🔲 None	Project Office
7. Have all required environm analyses been completed?	nental tests &	Х			ETAS attached			20. Handli Attach	ng Document → See Item 11 ed None	Samo Bil 2/18/05
8. Is all required assembly an subsystem level functional tes		Х			Performance Test Data Attached. Also see EIDP in item # 4.		21. Shortage List ☐ Attached ☐ None			
9. Have all piece parts, proce materials been approved by J		Х							rements Verification Matrix ed (See #4, #7, #8) None	
10. Does this hardware meet contamination control requirer		х				tion control and out-gassing		23. Qualification Status Attached None		
11. Are all shipping container special handling procedures re		X			*	as Attached Document D 26790 24.		24. Mate / Demate Record Attached None		
12. Is additional work required hardware to flight readiness?	d to bring this		Х					25. Operat	ing Log ed (See Item # 24)	
13. Is this hardware acceptable for flight?		X						26. MICD Attach	ed None	



SPIRE JFET Module S/N 013

RAL EIDP Table of Contents Versus JPL HRCR Check List Item Numbers

RAL EIDP Section Number	RAL EIDP Title	JPL HRCR Check List Item Number	Notes
1	Shipping Documents		Shipper and Final IR
2	Transportation, Packing, Handling & Integration Procedures	11	Special Handling Document D-26790
3	Certificate of Conformance / Delivery Review Board MOM		HRCR book is the C of C
4	As Built Configuration Status List	1 & 2	Assembly Drawings
5	List of Waivers	4	RFW (request for waiver) Attached
6	Copies of Waivers	4 & 7	RFW (request for waiver) Attached
7	List of Non-Conformance Reports		See RFW in 4 & 7
8	Copies of Non-Conformance Reports		See RFW in 4 & 7
9	Cleanliness Statement		Final IR QA Inspection
10	Operational Manual		NA
11	Top Level Drawings (inc. Family Tree)	14	Top Assembly Drawing
12	Interface Drawings	26	MICD Drawing
13	Functional, Block & Mechanical Drawings		NA
14	Electrical Circuit Drawings		NA
15	Serialized Components List		In build books – not shipped
16	Mass Properties/ Power Budget	HRCR Check List Page 1	Mass listed in HRCR check list
17	Qualification Status List / Test Matrix	23	Qualification Unit Test Matrix
18	Test Reports	4, 7, 8, 23	
19	Open Work / Deferred Work / Open Tests		NA
20	Calibration Data		NA
21	Historical Record	23	Qualification Unit Test Matrix
22	Manufacturing Logbook(s)		In build books – not shipped
23	Operating Time / Cycle Record	25	
24	Connector Mating Record	24	
25	Age Sensitive Items Record		NA
26	Pressure Vessels – History/Test Record		NA
27	Temporary Installation Record		NA
28	Reference List of EIDPs (Lower level)		NA
29	Other Useful Information		NA

JPL Hardware Requirements Certification Review (HRCR)

Junction Field Effect Transistor (JFET) Flight Module

10209750-1 S/N 013

SPIRE Element
Herschel Space Observatory Project

February 3, 2005

Configuration of Module, Boards & Membranes

Module 10209750-1	S/N 13	S/N 13
PWB 10209760-1	S/N 33	S/N 39
Membrane 10209758-1	J6.10.6	J6.15.4

Attachment of HRCR Items #1 Drawing Release Status

ALL ASSEMBLY & PARTS DRAWINGS ARE RELEASED IN PDMS

Released Drawings:

10209719-1	assembly built per released Rev. A drawing (studlock)
10209722-1	assembly built per released Rev. B drawing (interface drawing)
10209750-1	assembly built per released Rev. B drawing (module assy)
10209751-1	assembly built per released Rev. B drawing (chassis 1)
10209752-1	assembly built per released Rev. A drawing (chassis 2)
10209753-1	assembly built per released Rev. A drawing (chassis 3)
10209754-1	assembly built per released Rev. C drawing (mount)
10209756-1	assembly built per released Rev. B drawing (chassis lid)
10209757-1	assembly built per released Rev. A drawing (membrane)
10209758-1	assembly built per released Rev. A drawing (membrane assy)
10209759-1,-2	2,-4 redlined Rev. B drawing (gasket)
10209760-1	assembly built per released Rev. C drawing (board assembly)
10209761-1	assembly built per released Rev. C drawing (solder connector)
10209769-1	assembly built per released Rev. A drawing (stiffener)
10209777-1	assembly built per released Rev. B drawing (board)
10209858-2	assembly built per released Rev. A drawing (special fastener)
10217636-1	assembly built per released Rev. A drawing (clip)

Attachment of HRCR Item #4: EIDP

EI	DP	Cover	page I	For J	F	ET T	est	ing
----	----	-------	--------	-------	---	------	-----	-----

	Unit Identfication	_						
L	Name	:		M Module				
	Part#	:		750-1				
	S/N	:	#0	13				
	Environmemtal Testing							
	Livi oilliciitui resting	Г	Axes		Duration/#			
			Tested	Temp	of Cycle	Requirement	Source	Waiver
Н		H		remp	,		SSSD.	
	Random Vibration Test		X, Y, Z	Rm T	1 min/axis	X, Y, Z	JFET-DES-07	
		Γ					SSSD,	HR-SP-JPL-
	High Level Sine Vibe Test	L	None	NA	NA	X, Y, Z	JFET-DES-07	RFW-005
	Bakeout		NA	80 C	25 hrs	> 24 HRS		
	Thermal Cycles		NA	RmT to 80 K	2	Minimum 1	D-20549	
	Derformance Characteristics	-						
-	Performance Characteristics	_		Cifi	4:		P	Maire
	Power needed for <11 bad channels			Specific 11 mW/fa			Source	Waiver HR-SP-JPL-
	(Min Perf.)		7.15 mW	11 mW fo 7 mW for l		JEET-TEC	SSSD, -05, JFET-PER-02	RFW-004
	Power needed for <4 bad channels			11 mW fo		0, 21-120	SSSD.	
	(Design Value)		8.39 mW	7 mW for		JFET-TEC	-05, JFET-PER-02	
	Power needed for 100 %							
	Yield per unit		8.96 mW	N/A	4		NA	
	Median Noise at < 11 bad chs.		10.02 nV/rtHz	<15 nV/rtHz	<7 nV/rtHz	SSSD,	JFET-PER-01	
	Median Noise at < 4 bad chs.		7.98 nV/rtHz	Min	Design	SSSD,	JFET-PER-01	
	Median Noise at 100 % Yield.		6.77 nV/rtHz	Performance	Value	SSSD,	JFET-PER-01	
	# of Channels over the	Г					SSSD,	
	max. offset voltage	L	0	< 15 mV			BDA-DRCU-27	
	Common Mode Rejection Ratio		< -60 dB by design, as measured in EM4 uni			nit	SSSD, BDA-DRCU-11	
Н	Board Level Details							
ш				SN 033		rd SN 039		
Н		H		-JDD)		AA'-JDD')	Source	
Н	# Channels Tested	:	24		24	ļ	SSSD.	
	Median Noise at 3.5 mW		11.39	nV/rtHz	9.3	2 nV/rtHz	JFET-PER-01	
	# of good channels	Ė	11.00	68.7%	0.0	75 %	SSSD.	
	at 3.5 mW	:	16	Yield	18	Yield	JFET-PER-02	
	Power Needed for						SSSD,	
	100 % Yield	:	4.5 mW		4.46 mW		JFET-PER-02	
	Median Noise at High Power (w/ 100						SSSD,	
	% Yield)			V/rtHz	6.7	3 nV/rtHz	JFET-PER-01	
Н	Median Gain at High Power	H	0.	98		0.97	NA NA	
	Heater Resistance, 4K Reference value		2.00	kΩ	2	2.68 kΩ	NA	
	Definitions		2.00					
	Good Channels		Noise less than	a a min wasfe	annos velves e	f 15 p\//dU=		
	Yield		# of Good Cha	n a min. perform	narice value o	13 HV/IIIIZ		
	Filenames	·	, or odda ona	inieis / 24				
	Noise Measurements		IEET Modes	Noise post and				
	Source Voltages (RmT, 4K)			Noise_perf.pdf				
	Notes	·	3PE1_M0013_	Source_Voltage	e_Data.pdf			
43		_	a phagasta da d	on was Alf				
	The Base temperature for all performan							
2)	All Noise Measurements were made w	ith	the inputs shor	ted to ground				
3)	Type of membranes:		SN033:67 % C	veretched (Soli	id)	SN039: 30 % Ove	retched (Perforated)	

Attachment of HRCR Item #4: RFW (request for waiver)

		RFW/RFD Number:	HR-SP-JPL	RFW-014
Spacecraft / Project	Herschel	Originator's Name	Steve Tseng	
System / Experiment / Model	1.1 SPIRE	Signature / Date		
Sub-System	detectors	Request Type (Highlight applicable request)	Waiver (RFW)	Deviation (RFD)
Assembly	JFET modules	1.1.1.1 Organisation	Jet Propulsion	Laboratory
Sub-Assembly		Ref. Doc. / Drwg No.	SPIRE-JPL-P	RJ-000456
Item		References		
Serial No.		I/GIGIGIICG3		
RFW/RFD Title	JFET Power Dissipation s/n 01	13		

End Items(s) Affected (Hardware, Software)									
CI-Ni	ımber		Model(s)						
		PFN	Л						
Requirement / Interface Documents Affected									
Number	Issue	Date	App. Paragraph						
SPIRE-JPL-PRJ-0004456	3.2	7/1/03	JFET-PER-01						
			JFET-PER-02						
			JFET-TEC-05						
	CI-Nu Requirement / Interface Docu	CI-Number Requirement / Interface Documents Affect Number Issue	CI-Number PFN Requirement / Interface Documents Affected Number Issue Date						

Requirement states that dissipation of photometer JFETs is to be less than 7 mW average, while supplying 90% of channels with voltage noise < 15 nV/rtHz according to BDA-SSSD JFET-PER-01, JFET-PER-02, JFET-TEC-05. Measured JFET performance of the JFETs indicates that 7.15 mW of power dissipation will be required to meet the specified yield and noise performance specifications.

Other Items or Requirements (Potentially) Affected

Overall sensitivity of the bolometer sub-system is affected by JFET noise performance. JFET power dissipation impacts the heat sink temperature of the 3He refrigerator and may in turn increase the base detector temperature. Dissipation of JFETs affects power dissipation on cryostat.

Need for RFW/RFD and Rationale for Acceptance

Measured JFET performance of JFETs indicates that 7.15 mW of power dissipation will be required to meet the specified yield and noise performance specifications. JPL is unable to significantly alter the JFET fabrication process in order to meet the power specification without undue risk to the stated PFM/FS delivery dates. Furthermore, JPL requests a full system optimisation to revisit the noise and power requirements on the JFETs. The JFET modules can meet the noise design value with 100 % yield at 8.96 mW.

	Approved	Rejected	Name	Date
Engineering:				
Product Assurance:				
CCB-Chairman:				
Principal Investigator				
Product Assurance:				
Co-Investigator				
Prime Contractor				
ESA Project Office				

Attachment of HRCR Item #7: RFW (request for waiver)

				H	HR-SP-JPL-RFW-005		
Spacecraft / Project	Herschel		Originator's Name		Kalyani Sukhatme	Э	
System / Experiment / Model	SPIRE		Signature / Date				
Sub-System	detectors		Request Type (Highlight applicable reque	est)	Waiver (RFW)	Deviation (RFD)	
Assembly			Organisation		Jet Propulsion Laboratory		
Sub-Assembly			Ref. Doc. / Drwg No.		SPIRE-JPL-PI	RJ-000456	
Item			References				
Serial No.		References					
RFW/RFD Title	BDA and JFET module sine test deletion						
		-		,		-	

E	nd Items(s) Affected (Ha	rdware, Softwar	e)						
Name									
Bolometric Detector Assemblies				QM, PFM, FS					
JFET Modules			CC	QM, PFM, FS					
D	anninamant / Interfess De	annanta Affaat							
	equirement / Interface Do	_	1						
Specification/Drawing Title	Number	Issue	Date	App. Paragraph					
BDA-SSSD (SPIRE-JPL-PRJ-		3.2	Jan 7,	BDA-DES-10, JFET-DES-					
000456)			2003	07					
Descripti	on of Deviation / Discrep	ancy / Non-Con	formance						
High Level Sine- Vibe Test is not perforn	ned on these units								
Othe	r Items or Requirements	(Potentially) Aff	ected						

Need for RFW/RFD and Rationale for Acceptance

The hardware has to be qualified under a cold vibration test and is installed in the cold vibration facility for the purpose of the test. The high level sine vibration test configuration will put the hardware and the personnel at risk since the cold vibration facility is not structurally capable of withstanding the high levels. Obtaining additional resources (cost and schedule) for developing a new set-up is not feasible at this time.

	Approved	Rejected	Name	Date
JPL Engineering:				
JPL Product Assurance:				
CCB-Chairman:				
Principal Investigator				
Product Assurance:				
Co-Investigator				
Prime Contractor				
ESA Project Office				

Attachment of HRCR Item #7: ETAS (environmental test summary)

Note: The initial S/N 013 module originally failed test due to a failure on board 10209760-1 S/N 030 (Ref. ETAS No. 035 and a closed PFR No. Z85374). The failed board S/N 030 was subsequently replaced by board 10209760-1 S/N 039 into module S/N 013. Then module S/N 013 was then vibrated and has passed final performance tested (see ETAS No.HS036).

ETAS No. HS036

AND REAL PROPERTY AND ADDRESS OF THE PARTY O		OI AUTHOR	IZATION	AND SUMMAR	IT (ETAS)	
	AUTHOR	RIZATION SEC	TION			
PROJECT			LOG N	D.	AND THE RESERVE TO SERVE AND ADDRESS OF THE PARTY OF THE	
Herschel			HS036	3		
S JEET Modules S/N 13,145				DATE ISSUED 1/06/05		
REFERENCE DESIGNATION NUMBER	PART NO. (IF MULTIPLE, A 10209750-1	ATTACH LIST)	REV.		SERIAL NO. O13.045 4/2/05	
HARDWARE TYPE			PRE-EN	IVIRONMENTAL INSPEC	TION REPORT NUMBER (ATTACH IR)	
☐ EM QUAL ☐ FLIGHT ☐	FLIGHT SPARE	OTHER			· · · · · · · · · · · · · · · · · · ·	
WIRING HARNESS		PART NO.	REV.		SERIAL NO.	
☐ EM QUAL ☐ FLIGHT	EM SE					
TEST DESCRIPTION (CHECK ALL APPLICABLE)		_	TYPEC	F TEST		
	ACOUSTIC EMC	OTHER	_ 🔲 au	ALIFICATION	☐ FLIGHT ACCEPTANCE	
RANDOM VIBRATION THERMAL VAC.	THERMAL ATMOSPHERE		⊠ PR	OTO FLIGHT	RETEST	
WILL ALL TESTS/LEVES/DURATIONS REQUIRED BY TH	E PROJECT DOCUMENTS B					
YES NO (IF NO, ATTACH E		ENTER PROJ. DO	C. NO. AND REV			
HAS THE UNIT PASSED ALL PRE-ENVIRONMENTAL FU			_:.			
YES NO (IF NO, ATTACH E)		BRIEF EXPLANAT	ON			
HAVE ALL DESIGN ANALYSES BEEN COMPLETED AND						
YES NO (IF NO, ATTACH E)		BRIEF EXPLANAT	ON		· · · · · · · · · · · · · · · · · · ·	
IS THE TEST ARTICLE IDENTICAL TO OTHER FLIGHT U						
YES NO (IF NO, ATTACH E)	XCEPTIONS LIST)	BRIEF EXPLANAT	ON Stiffeners have	ve been added to the desig	n and includedon this unit	
ARE ALL PFRs AGAINST THIS UNIT CLOSED?						
YES NO (IF NO, ATTACH E)	XCEPTIONS LIST)	See PFR # Z85374	ON PFR's in proc	ess of closure. All issues	have been addressed and qualified.	
HAVE ALL WAIVERS AND ECRs BEEN APPROVED AND	ARE THEY INCORPORATED					
YES NO (IF NO, ATTACH EX		BRIEF EXPLANAT	ON			
COGNIZANT ENGINEERI	A Colombia C	4-	-7-05	ENVIRONMENTALDE	OWINEMENTS BYG. DATE	
Declaration of the second	Control of the Contro	MARY SECTIO	NOT THE PART OF THE SALE			
TEST AGENCY (IF MULTIPLE, ATTACH SUMMARY AND JPL Building 144	TEST DATES) TEST INITI. 1/10/04	ATION DATE AC	CUMULATED OP	ERATING HOURS PRIOF	TO FIRST ENVIRONMENTAL TEST	
SERIAL NUMBERS ACTUALLY TESTED	TEST TERM	NATION DATE OP	ERATING HOUR	S DURING ENVIRONMEN	TAL EXPOSURE	
5/N 0/3						
	TES					
		T DESCRIPTION				
VIBRATION ACOUSTIC	PYROSHOCK SHOCK		AL VACUUM	TEMPERATURE A	TMOSPHERE COTHER	
VIBRATION ACQUISTIC AXES: X Y Z	PYROSHOCK SHOCK AXES: X Y	Z PRESSURE	AL VACUUM <10E-5	☐ TEMPERATURE A	TMOSPHERE OTHER	
AXES: X Y Z		Z PRESSURE	<10E-5	☐ TEMPERATURE A	TMOSPHERE OTHER	
AXES: X Y Z SINE VIBRATION	AXES: X Y	Z PRESSURE	<10E-5	TEMPERATURE A	TMOSPHERE OTHER	
AXES: X Y Z SINE VIBRATION	AXES: X Y	Z PRESSURE 477K (10 K NO OF CYC	<10E-5 (.T) (ES: 2<-4 <-8	NO OF CYCLES:		
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS.	Z PRESSURE <77K (†• ii NO OF CYCI	<10E-5 (.T) (ES: 2<-4 <-8	NO OF CYCLES:	LATED DURATION (HRS.)	
AXES: X Y Z SINE VIBRATION	AXES: X Y	Z PRESSURE 477K (10 K NO OF CYC	<10E-5 (.T) (ES: 2<-4 <-8	NO OF CYCLES: EVEL (°c) AND ACCUMU HOT:°c,	LATED DURATION (HRS.) _h COLD;°c,h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS.	Z PRESSURE 277K (10 k NO OF CYC) ISOLATION MAGNETICS	<10E-5 (.T) (ES: 2<=1 <-8	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT:°C,	LATED DURATION (HRS.)	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. NIMENTAL TESTS?	Z PRESSURE 277K (10 k NO OF CYC) ISOLATION MAGNETICS	<10E-5 (.T) (ES: 2<-4 <-8	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT:°C,	LATED DURATION (HRS.) _h COLD;°c,h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. NIMENTAL TESTS?	Z HERM PRESSURE 477K (10 in NO OF CYC ISOLATION MAGNETICS LIST PFR NO	(10E-5 (.T) (ES: 2<-1 <- 8 TEMP. L	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION	LATED DURATION (HRS.) _h COLD;°c,h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. INMENTAL TESTS? (CEPTIONS LIST) NS COMPLETE?	Z PRESSURE 2 PRESSURE 277K (10 ii NO OF CYCI ISOLATION MAGNIETICS LIST PFR NO	<10E-5 (.T) (ES: 2<=1 <-8	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION	LATED DURATION (HRS.) _h COLD;°c,h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. NIMENTAL TESTS? (CEPTIONS LIST) INS COMPLETE?	Z PRESSURE 2 PRESSURE 277K (10 ii NO OF CYCI ISOLATION MAGNIETICS LIST PFR NO	(10E-5 (.T) (ES: 2<-1 <- 8 TEMP. L	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION	LATED DURATION (HRS.) _h COLD;°c,h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. INMENTAL TESTS? (CEPTIONS LIST) NS COMPLETE? (COPY OF THE INSPECTION)	Z PRESSURE 37K (10 in No of cycl I ISOLATION MAGNETICS LIST PFR NO LIST PFR NO	C10E-5 C.T) ES: 20C-1 CB TEMP, L	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION	LATED DURATION (HRS.) _h COLD;°c,h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. RAD. EMIS. COPTIONS LIST) NS COMPLETE? COPY OF THE INSPECTION O, ATTACH EXPLANATION) EVED?	Z PRESSURE 37K (10 in No of cycl I ISOLATION MAGNETICS LIST PFR NO LIST PFR NO	(10E-5 (.T) (ES: 2<-1 <- 8 TEMP. L	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION	LATED DURATION (HRS.) _h COLD;°c,h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. RAD. EMIS. CCEPTIONS LIST) NS COMPLETE? COPY OF THE INSPECTION O, ATTACH EXPLANATION) EVED? CCEPTIONS LIST)	Z PRESSURE 37K (10 in No OF CYC) ISOLATION MAGNETICS LIST PER NO	C10E-5 CT) CES: 2C-1 C-8 TEMP, L DS. / BRIEF EXPL DS. / BRIEF EXPL	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION ANATION	LATED DURATION (HRS.) _h COLD;°c,h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. NIMENTAL TESTS? (CEPTIONS LIST) NS COMPLETE? LOOPY OF THE INSPECTION (ATTACH EXPLANATION) EVED? (CEPTIONS LIST) TED. SEE THE ATTACHED S	Z PRESSURE Z PRESSURE Z7K (10 in NO OF CYC) ISOLATION MAGNETICS LIST PER NO LIST PER NO LIST PER NO SUMMARY FOR ACTION	C10E-5 CT) CES: 2C-1 CES TEMP, L CES: 2C-1 C	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION ANATION	LATED DURATION (HRS.) h COLD: "c, h h COLD: "c, h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. NIMENTAL TESTS? (CEPTIONS LIST) NS COMPLETE? LOOPY OF THE INSPECTION (ATTACH EXPLANATION) EVED? (CEPTIONS LIST) TED. SEE THE ATTACHED S	Z PRESSURE Z PRESSURE Z7K (10 in NO OF CYC) ISOLATION MAGNETICS LIST PER NO LIST PER NO LIST PER NO SUMMARY FOR ACTION	C10E-5 CT) CES: 2C-1 CES TEMP, L CES: 2C-1 C	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION ANATION ANATION TO BE TAKEN.	LATED DURATION (HRS.) h COLD: "c, h h COLD: "c, h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. NIMENTAL TESTS? (CEPTIONS LIST) NS COMPLETE? LOOPY OF THE INSPECTION (ATTACH EXPLANATION) EVED? (CEPTIONS LIST) TED. SEE THE ATTACHED S	Z PRESSURE Z PRESSURE Z7K (10 in NO OF CYC) ISOLATION MAGNETICS LIST PER NO LIST PER NO LIST PER NO SUMMARY FOR ACTION	C10E-5 CT) CES: 2C-1 CES TEMP, L CES: 2C-1 C	NO OF CYCLES: EVEL ("c) AND ACCUMU HOT: "c, HOT: "c, ANATION ANATION ANATION TO BE TAKEN.	LATED DURATION (HRS.) h COLD: "c, h h COLD: "c, h	
AXES: X Y Z SINE VIBRATION	AXES: X Y SHOCKS/AXIS: COND. EMIS. RAD. EMIS. RAD. EMIS. COPTIONS LIST) NS COMPLETE? COPY OF THE INSPECTION O, ATTACH EXPLANATION) EVED? COPTIONS LIST) TED. SEE THE ATTACHED S TE TECHNICAL MGR./INS	Z PRESSURE 37K (10 in No OF CYC) I SOLATION MAGNETICS LIST PER INC	C10E-5 CT) CES: 20= 1 COS TEMP, L SC. / BRIEF EXPL SC. / BRIEF EXPL SC. / BRIEF EXPL SC. / BRIEF EXPL DATE	NO OF CYCLES: EVEL (°G) AND ACCUMU HOT:	LATED DURATION (HRS.) _h COLD:c,h h COLD:c,h	
AXES: X Y Z SINE VIBRATION	SHOCKS/AXIS: COND. EMIS. RAD. EMIS. RAD. EMIS. COPTIONS LIST) NS COMPLETE? COPY OF THE INSPECTION ATTACH EXPLANATION) EVED? COPTIONS LIST) TECHNICAL MGR./INS E ENVIRONIMENTAL TESTS	Z PRESSURE LIST PER NO LI	COE-5 CES: 20-1 CES TEMP. L DES. / BRIEF EXPL	NO OF CYCLES: EVEL (°G) AND ACCUMU HOT:	LATED DURATION (HRS.) h COLD:ec,h h COLD:ec,h DUIREMENTS ENG. DATE	

ETAS No. HS036 (continued)

PAGE 1 JPL 2683 R 1/98 FF



ENVIRONMENTAL TEST AUTHORIZATION AND SUMMARY (ETAS)

OTHER AUTHORIZATION PROVISIONS AND EXPLANATIONS

Thus is a 3-axis warm vibration test (room temp) done on the JFET flight modules SNOWE and 013. The test will be done with the JFET unit mounted inside a mock-up JFET rack. The unit will be assessed both before and after the test with visual inspections and electrical checkouts. 3 response accelerometers will be mounted onto the JFET rack in order to give response data.

2 to 3 vacuum thermal cycles will also be completed.

This unit a 3-axis ambient vibe already completed. An electrical problem was discovered after vibe and PFR # Z85374 was generated. The problematic channel was removed from the flight wiring scheme and replaced with a healthy channel. This vibe will act to qualify the unit for flight. This unit, therefore, will see 2x 3axis vibe tests.

ETAS No. HS036 (continued)

÷ ·	COMMENTS		PAGE 3 JPL 2683 R 1/86 FF
(ETAS)	PASS/ FAIL		
D SUMMARY IARY	TEST		
FAL TECT UTHORIZATION AND SUI	DATE TEST PERFORMED		
ENVIRONMENTAL TEC UTHORIZATION AND SUMMARY (ETAS) ENVIRONMENTAL TEST SUMMARY	TEST ENVIRONMENT LEVELS & DURATION	Thinute Random Vibe Frequency Spec [H2] [g*2.Hz] 20 0.01 20 0.05 300 0.0214 500 0.00214 500 0.00214 500 0.00214 2000 4.99 0.00214 2000 2000 4.99 0.00214 2000 4.99 0.00214 2.3000 4.90 2.3000 4.	
ENVIE	ETAS	HSO36	
	N/S	4	
	HARDWARE	SPIRE JFET (10209750-1)	

ETAS No. HS035

ENVIRONMENTAL TEST AUTHORIZATION AND SUMMARY (ETAS) AUTHORIZATION SECTION PROJECT LOG NO. HS035 Herschel YSTEM/ASSEMBLY TITLE DATE ISSUED AE JFET Modules S/N 13,14 12/03/04 REFERENCE DESIGNATION NUMBER PART NO. (IF MULTIPLE, ATTACH LIST) REV. SERIAL NO. 10209750-1 013,014 HARDWARE TYPE PRE-ENVIRONMENTAL INSPECTION REPORT NUMBER (ATTACH IR) ☐ EM QUAL ☑ FLIGHT ☐ FLIGHT SPARE OTHER WIRING HARNESS PART NO. SERIAL NO: ☐ EM QUAL EM SE FLIGHT TEST DESCRIPTION (CHECK ALL APPLICABLE) TYPE OF TEST SINE VIBRATION PYROSHOCK ACOUSTIC EMC OTHER QUALIFICATION ☐ FLIGHT ACCEPTANCE RANDOM VIBRATION THERMAL VAC. THERMAL ATMOSPHERE PROTO FLIGHT RETEST WILL ALL TESTS/LEVES/DURATIONS REQUIRED BY THE PROJECT DOCUMENTS BE PERFORMED ON THIS UNIT? ENTER PROJ. DOC. NO. AND REV. X YES NO (IF NO, ATTACH EXCEPTIONS LIST) HAS THE UNIT PASSED ALL PRE-ENVIRONMENTAL FUNCTIONAL TESTS: BRIEF EXPLANATION X YES NO (IF NO, ATTACH EXCEPTIONS LIST) HAVE ALL DESIGN ANALYSES BEEN COMPLETED AND REQUIRED CHANGES BEEN IMPLEMENTED? X YES NO (IF NO, ATTACH EXCEPTIONS LIST) BRIEF EXPLANATION IS THE TEST ARTICLE IDENTICAL TO OTHER FLIGHT UNITS? NO (IF NO, ATTACH EXCEPTIONS LIST) BRIEF EXPLANATION Stiffeners have been added to the design and includedon this unit YES ARE ALL PFRs AGAINST THIS UNIT CLOSED? BRIEF EXPLANATION PFR's in process of closure. All issues have been addressed and qualified NO (IF NO, ATTACH EXCEPTIONS LIST) except for ongoing diagnosis of last two units (12,13) HAVE ALL WAIVERS AND ECRS BEEN APPROVED AND ARE THEY INCORPORATED? BRIEF EXPLANATION NO (IF NO, ATTACH EXCEPTIONS LIST) TEST AUTHORIZED BY ENVIRONMENTAL BEQUIREMENTS ENG. COGNIZANT ENG DATE | TECHNICAL MGR/INSTR MRG/PI PREP REP DATE DATE certin A 12/2/04 SUMMARY SECTION TEST AGENCY (IF MULTIPLE, ATTACH SUMMARY AND TEST DATES) TEST INITIATION DATE ACCUMULATED OPERATING HOURS PRIOR TO FIRST ENVIRONMENTAL TEST JPL Building 144 12/07/04 SERIAL NUMBERS ACTUALLY TESTED TEST TERMINATION DATE OPERATING HOURS DURING ENVIRONMENTAL EXPOSURE TEST DESCRIPTION VIBRATION ACOUSTIC PYROSHOCK SHOCK THERMAL VACUUM TEMPERATURE ATMOSPHERE OTHER AXES: X Y Z AXES: X Y PRESSURE: <10E-5 SINE VIBRATION 1 cacle <77K NO OF CYCLES: 2<= # <=8 NO OF CYCLES: RANDOM VIBRATION X X SHOCKS/AXIS: TEMP, LEVEL (°c) AND ACCUMULATED DURATION (HRS.) EMC COND. SUSC. COND. EMIS. ☐ ISOLATION HOT: °C. h COLD: ☐ ESD RAD. SUSC. RAD, EMIS. MAGNETICS HOT: COLD: WERE THERE ANY PFRs GENERATED DURING ENVIRONMENTAL TESTS? LIST PER NOS. / BRIEF EXPLANATION NO (IF NO, ATTACH EXCEPTIONS LIST) ARE THE POST ENVIRONMENTAL DAMAGE INSPECTIONS COMPLETE? LIST PFR NOS. / BRIEF EXPLANATION NO (IF YES, ATTACH A COPY OF THE INSPECTION REPORTS. IF NO, ATTACH EXPLANATION) WERE ALL PLANNED TESTS/LEVELS/DURATIONS ACHIEVED? LIST PFR NOS. / BRIEF EXPLANATION NO (IF NO, ATTACH EXCEPTIONS LIST) TESTS HAVE NOT BEEN SUCCESSFULLY COMPLETED. SEE THE ATTACHED SUMMARY FOR ACTIONS THAT INEED TO BE TAKEN. COGNIZANT ENGINEER DATE | TECHNICAL MGR/INSTR MRG/PI PREP REP DATE | ENVIRONMENTAL REQUIREMENTS ENG. DATE , HARDWARE HAS SUCCESSFULLY COMPLETED THE ENVIRONMENTAL TESTS LISTED ON THIS FORM OR REMAINING ACTIONS HAVE BEEN TAKEN, INCLUDING RETEST. COGNIZANT ENGINEER DATE | TECHNICAL MGR./INSTR MRG./PI PREP REP DATE ENVIRONMENTAL REQUIREMENTS ENG. 2/7/05

ETAS No. HS035 (continued)

PAGE 1 JPL 2683 R 1/98 FF



ENVIRONMENTAL TEST AUTHORIZATION AND SUMMARY (ETAS)

OTHER AUTHORIZATION PROVISIONS AND EXPLANATIONS

nis is a 3-axis warm vibration test (room temp) done on the JFET flight modules SN012 and 013. The test will be done with the JFET unit mounted inside a mock-up JFET rack. The unit will be assessed both before and after the test with visual inspections and electrical checkouts. 3 response accelerometers will be mounted onto the JFET rack in order to give response data.

2 to 3 vacuum thermal cycles will also be completed.

5/N 013 failed (285374)-problem found during thermal cycle.
Remark to be done or Thermal (ETAS HEOSE)

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ETAS No. HS035 (continued)

(9	COMMENTS		PAGE 3 JPL 2683 R 1/98 FF
	Y (ETAS)	PASS/ FAIL		
	D SUMMAR	TEST		
	AL TES JTHORIZATION AND SUI ENVIRONMENTAL TEST SUMMARY	DATE TEST PERFORMED		
	ENVIRONMENTAL TES JTHORIZATION AND SUMMARY (ETAS) ENVIRONMENTAL TEST SUMMARY	TEST ENVIRONMENT LEVELS & DURATION	X, Y, and Z 1 minute Random Vibe Frequency Spec [Hz] 20 0.01 100 0.05 300 0.0214 500 0.00214 500 0.00214 500 0.00214 5000 Each axis 1/4 g sine sweep 20-2000 Hz each axis 1 cycles. <10E-5 mbar, <70K	
	ENAI	ETAS	HSO35	
		N/S	4 4	
(1	HARDWARE	SPIRE JFET (10209750-1)	

Attachment of HRCR Item #8: Test Data - Source Voltage & Noise For Module 13

JFET SOURCE VOLTAGE MEASUREMENT

Perf Test Post Vibe, post bake, SN13 module, grn dewar, Helium.

				5 module, grn dew				
Date			2005		2005			
T, plate			K		K			
1/44			K	4				
Vdd Vss			.5		.5			
∨ss Vdď		2.729	.5	2.688	.5			
Vaa'		-1.224		-1.183				
ldd		1.0	458		204			
lss			443		029			
SN		3	3	3	9			
Channel #			DELTA		DELTA			
1	a	0.942	0.007	0.551	0.006			
	b a	0.949 0.663		0.557 0.779				
2	b	0.670	0.007	0.782	0.003			
	a	0.786		1.062				
3	b	0.777	0.009	1.067	0.005			
4	а	1.603	0.044	0.787	0.004			
4	b	1.589	0.014	0.786	0.001			
5	а	0.602	0.012	1.001	0.001			
	b	0.590	0.012	1.002	5.501			
6	a	1.274	0.013	0.721	0.005			
	b	1.287		0.716				
7	a b	0.672 0.672	0	0.921 0.921	0			
		1.215		0.733				
8	a b	1.204	0.011	0.731	0.002			
	a	1.465		0.972				
9	b	1.459	0.006	0.965	0.007			
10	а	0.860	0.002	0.544	0.008			
10	b	0.862	0.002	0.536	0.000			
11	а	0.679	0.008	0.839	0.001			
- 11	b	0.687	. 5.555	0.840	0.001			
12	a	0.762	0.002	1.036	0.001			
	b	0.764		1.037				
13	a	0.998 0.998	0	0.765 0.762	0.003			
	b a	0.739		0.762				
14	b	0.740	0.001	0.285	0.004			
	a	0.710		0.672				
15	b	0.717	0.007	0.674	0.002			
16	а	0.693	0.002	0.667	0			
10	b	0.691		0.667	3			
17	а	0.719	0.002	0.771	0.001			
	b	0.721	. 5.502	0.772	5.501			
18	a	0.677	0	0.804	0			
	b	0.677 0.978		0.804 0.699				
19	a b	0.978	0.006	0.698	0.001			
	a	0.868		0.713				
20	b	0.871	0.003	0.712	0.001			
21	a	0.679	0.000	0.919	0.004			
21	b	0.677	0.002	0.923	0.004			
22	а	0.676	0.002	0.849	0.005			
	b	0.678	5.002	0.854	3.003			
23	a	0.707	0	0.699	0			
	b	0.707		0.699				
24	a	0.671	0.002	0.707 0.710	0.003			
	b	0.673		0.710				

Attachment of HRCR Item #8: Test Data - Source Voltage & Noise

Board S/N 033 in Module S/N 013

]	Pwr1	Pwr2	Pwr3	Pwr4	Pwr5	Pwr5b	Pwr7	Pwr8	Pwr9	Pwr10	Pwr11
Vdd (V)	3	2.9	2.8	2.8	2.8	2.8	2.8	2.8	2.8	2.8	2.8
Vss (V)	-1.5	-1.8	-1.7	-1.6	-1.65	-1.63	-1.55	-1.5	-1.4	-1.45	-1.35
Vdd' (V)	2.718	2.583	2.494	2.5066	2.5006	2.503	2.513	2.519	2.5309	2.5248	2.5369
Vss' (V)	-1.224	-1.488	-1.401	-1.3133	-1.3569	-1.33396	-1.2688	-1.2249	-1.1379	-1.1812	-1.0934
ldd (mA)	1.0864	1.2244	1.1761	1.1292	1.1527	1.1433	1.1056	1.0818	1.0352	1.0583	1.011
Iss (mA)	1.0442	1.1825	1.1342	1.0879	1.111	1.1019	1.0641	1.0407	0.9939	1.0173	0.9699
I (mA)	1.0653	1.20345	1.15515	1.10855	1.13185	1.1226	1.08485	1.06125	1.01455	1.0378	0.99045
P (mW)	4.1994126	4.89924495	4.49930925	4.234550145	4.36611138	4.307371296	4.10268573	3.973213875	3.72218104	3.8460868	3.595630635
Channel Num			Vn @150 Hz	Vn @150 Hz	Vn @150 Hz	Vn @150 Hz	Vn @150 Hz	Vn @150 Hz	Vn @150 Hz	Vn @150 Hz	Vn @150 Hz
Channel: 1	5.98	7.00	6.85	6.45		6.53	6.76	6.91	6.45		7.15
Channel: 2	7.59	6.62	6.46	7.33		5.50		7.37	12.20		13.27
Channel: 3	13.51	7.03	8.49	12.53	9.22	11.33		20.15	16.74	16.08	14.92
Channel: 4	5.68	4.70	5.02	6.52		4.91	5.55	6.13	6.02	5.38	6.25
Channel: 5	7.97	7.70	6.89	7.45		6.36		10.73	16.26	12.09	21.97
Channel: 6	5.87	5.52	5.52	5.89	5.26	5.80		6.96	9.42	8.30	12.01
Channel: 7	5.61	6.30	6.06	7.14	6.93	6.12		7.80	10.10	8.17	13.73
Channel: 8	5.24	5.89	6.48	5.04	5.88	5.94	5.93	5.56	6.01	6.13	5.44
Channel: 9	4.96	5.25	4.56	6.01	5.76	6.20	5.62	7.24	7.92	7.27	8.20
Channel: 10	22.43	7.45	11.04	18.05	14.87	17.01	25.80	30.10	43.71	40.94	43.01
Channel: 11	12.20	11.34	11.67	10.26	12.17	11.67	12.25	11.12	16.01	12.74	18.55
Channel: 12	13.78	9.82	12.77	13.96	13.07	14.28	14.22	13.15	12.18	12.40	9.92
Channel: 13	8.91	6.13	7.25	7.60	6.50	8.39		10.54	22.91	17.76	29.94
Channel: 14	8.79	13.83	14.76	10.88	11.10	11.31	9.93	8.99	9.33		8.62
Channel: 15	5.61	5.80	5.87	6.87	4.71	5.97	6.04	5.49	8.23	6.53	7.42
Channel: 16	10.43	8.73	9.23	9.83	9.35	10.60		12.54	11.45	11.58	15.57
Channel: 17	7.99	6.01	6.73	6.91	5.94	6.90		8.28	13.60		18.10
Channel: 18	8.93	6.39	6.10	9.46		8.53	11.53	11.52	11.26		10.12
Channel: 19	6.69	6.93	7.31	6.80	6.07	6.67	7.41	6.90	6.95		8.75
Channel: 20	5.87	6.78	5.35	5.20		5.55		5.78	7.54	6.42	9.21
Channel: 21	14.38	7.07	8.35	15.55	9.71	12.22		25.90	42.32	37.64	49.61
Channel: 22	25.96	8.36	12.77	19.63	18.32	21.40	23.67	37.33	43.57	36.72	45.54
Channel: 23	5.57	6.39	5.78	5.97	6.57	5.58		7.00	10.38	8.62	10.78
Channel: 24	7.12	7.03	6.30	5.73	6.97	6.98		6.79	9.48	7.29	8.45
Median	7.78	6.85	6.79	7.24		6.78		8.04	10.82	10.18	11.39
Overall Mean	9.46	7.25	7.82	9.05	8.38	8.82		11.68	15.00		16.52
Good Mean	8.12	7.25	7.82	7.80		7.88	8.12	8.34	9.32	8.84	9.64
MP Reqd	0.00	4.00	4.00		15				6.74	6.75	0.07
Yield	0.92	1.00	1.00	0.88	0.96	0.92		0.83	0.71	0.75	0.67
# Good Ch.	22	24	24	21	23	22		20	17	18	16
# Bad Ch.	2	0	0	3	1	2	4	4	7	6	8

Attachment of HRCR Item #8: Test Data - Source Voltage & Noise

Board S/N 039 in Module S/N 013

	Pwr1	Pwr2	Pwr3	Pwr4	Pwr5	Pwr5b	Pwr7	Pwr8	Pwr9
Vdd (V)	2.8	2.8	2.8	2.8	2.8	2.8	2.8	2.8	2.8
Vss (V)	-1.5	-1.4	-1.3	-1.2	-1.1	-1.15	-1.17	-1	-1.16
Vdd' (V)	2.479	2.4932	2.5074	2.5218	2.5361	2.529	2.5259	2.5509	2.5276
Vss' (V)	-1.184	-1.099	-1.013	-0.927	-0.841	-0.884	-0.902	-0.755	-0.893
Idd (mA)	1.236	1.1816	1.1264	1.0715	1.0156	1.0438	1.0549	0.9596	1.0495
Iss (mA)	1.1992	1.145	1.0901	1.0352	0.9795	1.0077	1.0188	0.9238	1.0133
I (mA)	1.2176	1.1633	1.10825	1.05335	0.99755	1.02575	1.03685	0.9417	1.0314
P (mW)	4.4600688	4.17880626	3.9014833	3.63279348	3.36882611	3.50088475	3.554218115	3.11316603	3.52800684

Channel Num			Vn @150 Hz						
Channel: 1	7.41	9.60	6.33	10.01		9.07	6.90	14.55	
Channel: 2	6.80	7.59	6.90	9.83	6.16	5.26	7.57	12.43	6.53
Channel: 3	5.31	6.73	8.54	13.49	18.95	15.28	14.78		16.88
Channel: 4	12.01	12.84	14.70	13.24	16.23	17.53	14.73	15.05	15.17
Channel: 5	9.02	10.94	15.62	21.46	21.38	18.11	16.58	33.71	19.00
Channel: 6	5.61	5.87	8.46	11.76	23.60	17.51	13.36	44.30	15.48
Channel: 7	7.34	8.93	6.29	5.81	8.65	6.88	7.45	15.41	5.78
Channel: 8	6.58	8.64	6.51	7.15		7.75			7.80
Channel: 9	7.01	5.94	6.46	5.71	6.96	7.52	5.60		6.10
Channel: 10	6.65	8.15	9.62	8.22	8.59	8.16	8.32	14.36	9.36
Channel: 11	6.56	8.20	9.83		16.03	13.70			13.80
Channel: 12	5.54	7.84	6.37	7.41	7.49		5.83	13.26	8.79
Channel: 13	12.10	14.19		11.40	16.36	14.21	13.47	20.24	12.53
Channel: 14	6.41	9.14	9.12	8.51	10.66	8.20			9.05
Channel: 15	11.78	19.69	36.78	39.73	39.37	43.94		28.49	41.29
Channel: 16	6.97	7.36	8.62	9.33		9.86	9.73		8.87
Channel: 17	9.88	16.83	28.79	46.50	48.22	50.44	54.57	48.85	52.42
Channel: 18	7.40	11.92	6.63						9.21
Channel: 19	5.93	11.77	7.53			9.93			8.15
Channel: 20	5.80	5.69	6.03	9.74		7.38			6.95
Channel: 21	6.60	5.94	6.30	8.89		7.98	6.51	10.68	9.23
Channel: 22	6.54	6.99	6.15		9.00	9.57	6.54		9.30
Channel: 23	7.27	5.16	6.22	13.36		11.46	10.42	11.37	11.39
Channel: 24	6.40	6.71	5.90	9.10			5.72	7.68	6.26
Median	6.73	8.18							
Overall Mean	7.45	9.28	10.28				12.65		13.21
Good Mean	7.45	8.46	7.89	9.66		8.80	9.10	12.16	8.72
MP Reqd					15				
Yield	1.00	0.92	0.88						
# Good Ch.	24	22	21	21	16	18	21	12	18
# Bad Ch.	0	2	3	3	8	6	3	12	6

Attachment of HRCR Item # 9: SPIRE MIUL Cover Page

MIUL = Material Identification & Utilization List

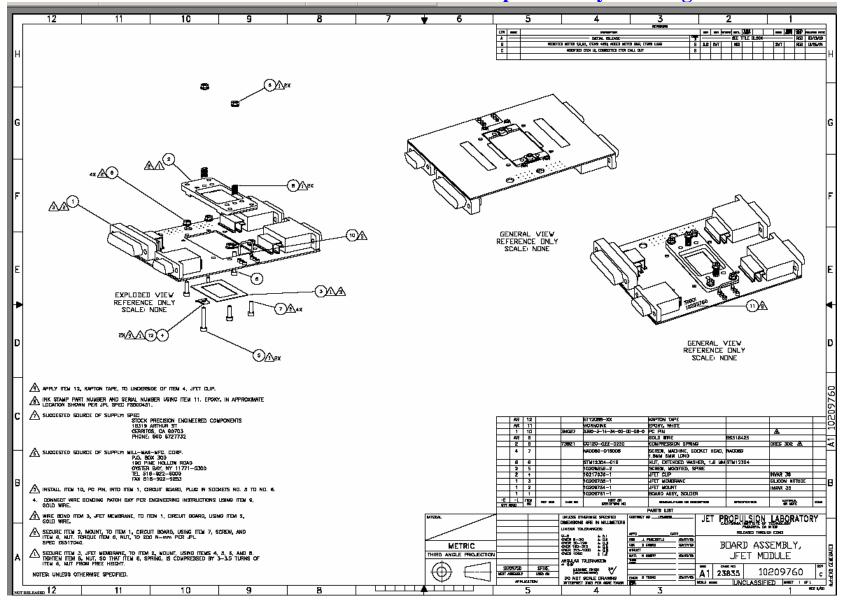
Declared Materials List and Processes List are not included in this HRCR

Materials and Processes List
ODIDE.
SPIRE
JPL D-25725
01 2 2 20/20
REV B
1/05/04
This technical data is export controlled under U.S. law and is being transferred by JPL to ES
for use exclusively on the Herschel/Planck projects. The information may not be used for a
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written approval of NASA.
21//1/
Reviewed by:
M. Knopp M&P Engineer
mi taropp man Engineer

Attachment of HRCR Item #11:

See End of This HRCR Package for "JFET Module Handling Document"

Attachment of HRCR Item # 14: JFET Module Top Assembly Drawing 10209750-1



Attachment of HRCR Item #23: Qualification Compliance Test

Qualification Model JFET Module

		EID	P Coverpage	For JFET Te	sting		
Unit Identfication							
Name	1:	JFET Q	M Module				
Part#	:		9750-1				
S/N	:	#(001				
Environmemtal Testing							
Environmental resting	т	Axes		Duration/# of			
		Tested	Temperature	Cycle	Requirement	Source	Waiver
	\vdash		remperature		requirement	SSSD.	
Random Vibration Test		X, Y, Z	100 K	2 min/axis	X, Y, Z	JFET-DES-07	
	T					SSSD,	HR-SP-JP
High Level Sine Vibe Test		None	NA	NA	X. Y. Z	JFET-DES-07	RFW 005
Bakeout	Т	NA	80 C	72 Hours	80C, 72 Hrs	D-20549	
Thermal Cycles		NA	RmT to 80 K	27	Minimum 15	D-20549	
ŕ							
Performance Characteristics	•						
	_		Specif	ication	S	ource	Waiver
Power needed for <11 bad	needed for <11 bad 11 mW for CQM,						RFW in
channels (Min Perf.)	L	9.1 mW	7 mW for	PFM/FS	JFET-TEC-0	5, JFET-PER-02	process
Power needed for <4 bad			11 mW f	or CQM,	s	SSD,	
channels (Design Value)		10.8 mW	7 mW for	PFM/FS	JFET-TEC-0	5, JFET-PER-02	
Power needed for 100 %							
Yield per unit		13.5 mW	N	A		NA	
Median Noise at < 11 bad chs.		7.13 nV/rtHz	<15 nV/rtHz		SSSD, J	FET-PER-01	
Median Noise at < 4 bad chs.		6.1 nV/rtHz	Min	<7 nV/rtHz	SSSD, J	FET-PER-01	
Median Noise at 100 % Yield.	Т	6.97 nV/rtHz	Performance	Design Value	SSSD, J	FET-PER-01	
# of Channels over the	П		< 15 mV for C0	2M		SSSD,	
max. offset voltage		0	< 15 mV for PF	M/FS		BDA-DRCU-27	
						SSSD,	
Common Mode Rejection Ratio		< -60 dB by d	esign, as meas	ured in EM4 un	it	BDA-DRCU-11	
Board Level Detail							
		Board	SN 001			Source	
# Channels Tested	:	24					
						SSSD,	
Median Noise at 3.5 mW	:	18 n	V/rtHz			JFET-PER-01	
# of good channels						SSSD,	
at 3.5 mW	:	7	29% Yield	L		JFET-PER-02	
Power Needed for						SSSD,	
100 % Yield	:	6.75 mW		ļ		JFET-PER-02	
Median Noise at High Power (w/			377.451			SSSD,	
100 % Yield)	\vdash		nV/rtHz	ļ		JFET-PER-01	
Median Gain at High Power	\vdash	0	.98	ļ		NA	
	\vdash						
	⊢						
Definitions	_						
Good Channels	:		a min. performan	ice value of 15 n\	//rtHz		
Yield	:	# of Good Char	nels / 24				
Filenames	\perp						
Noise Measurements	:	QualJFETPost\	/ibeNoise_Summ	ary.pdf			
Notes							
The Base temperature for all performa	ance	characterization	n was 4K				
All Noise Measurements were made v	vith	the inputs shorte	ed to ground				

Attachment of HRCR Item # 24 & #25: Mate/Demate & Operation Logs

Date	Time	AIDS	Power	Mate	Demate	Transport	Notes
区 105		244681					2 82
7/05		2 (100)	×	×			103 -> 183
12/05		C.		~	-		is he each board, wrm S.V.
12/05		CI		,			3 axis shake, morn (pump out
12/05		A. J.				*	144 -> 183
19/05		244739	3	X			install into gra derior
19/05		Cr.	×				is he pack bond, were S.V.
20		"	X				8 Ws brd 33 noise
21		r	Χ	·			4 ks, cr, cr
21		~	X				8 hrs, brd 34, maise
22		-	⋋				4 hrs, bod 34, noise
21	· · · · · · · · · · · · · · · · · · ·	~					3 hrs, brd 33, gain + 3 CMRK
22		- ~					3 ks, brd 34, gah + CMRR
24	· · · · · · · · · · · · · · · · · · ·	4	×				. 5 hr each bod, worm 5. V.
24		6			~		187 - N. EACH WAR, W. S.V.
-					X	×	183 -> 103, finished testing
	•				:		
					·		
	:						
			-				

Attachment of HRCR Item # 24 & #25: Mate/Demate & Operation Logs (continued)

Date	Time	AIDS	Power	Mate	Demate	Transport	Notes
1/24		24 4404				:	103 -> 158
124		-					pring out
126	1.	Ce	42 ×			:	30 to 80°C
/27		· · · · ·					turn heat off (25 hr bakeni
1/28		-(1587 183
130			X	×			. 5 kg , each board, wim 5, V.
153		244448					install into shake facility
2/7		"				X	183 -> 144
17	11 1						3 axis worm shake (fund out twice
217		c				×	144 -> 183
·							
17		244449	14.	χ			Install thto gra down
18		~			:		prop out, go cold
.19		/	×				4 hrs, bod 36, noise
2/10	:	~	× .				10 kg, a
113		~/	X				10 kg brd 37 noise
2/14		~	X				3 kg //
-114		CI	χ			:	3 Wrs, or gah, CMRR
1/14			Χ.		.:		3 hrs, or gah, CMRR 3 ws, bod 36, gah, CMRR
	<u> </u>						
117					Χ	×	183 -> 103
·.							
	<u> </u>						
· · · · · · · · · · · · · · · · · · ·		1					

Attachment of HRCR Items # 24 & # 25: Mate/Demate & Operation Logs (PWB S/N 033)

OPERATION LOG SHEET -- SPIRE JFET BOARDS MODULE

Mod. 13

DATE	TIME	TECH	PWR	PWR		MA	TE			DEM	ATE			NOTE
DATE	TIME	TECH	ON	OFF	JAA	JBB	JCC	JDD	JAA	JBB		JDD	TRANSFORT	NOTE
-15-04	MA00:7	103199			V	~	~	-	K					GND GHASSIS - SAVER ON
-19-4	-0-411	Man												GND CHASSIS - 11
	8:00	NH												SND9 CHASSIS 11
16-04		NIN	V	V										SOURCE TEST "
-22-04		Nilpy	,		~				1	ir	V	1		REMOVE STUEP
-22-04		NAW			V	V	V	V	V	1	1	V		GND 9 CHAS-815 TEST
-16-04		ST			V	V	V	V						GND & CHASSIS TEST
-16-04		ST	V	1			V	2			1	~		SOURCE TEST
-23-04		ST			1	V	i	0			V	0		GND & CANSONS
1-23-04		ST	V	V			i	V	V	i	1			SOUPLETEST
0-12-04		NAM			V	i	i	~			i	in		CAND & CHASSYS
0-12-04		NN	6	-			V	i	V	V				SOUPCE TEST
1-11-04		NM			V	i	i	i			v	i		GND 9 CAMS825
1-11-04		NYN	V	·			V	V	V	in				GOUPEE TEST
-17-04		NM			V	L	V	~			V	V		GNDS CHASSIS
1417-04		N.M	1	~			V	V			-	~		GOUPCE TEST
2-17-04		NW			V	î	V	V	Ť		V	V		GNP & CHIISSES
17.04		NW	·c	~			V	U	V	V	V	U	y	SOUPCE TEST
- 3-05	7:00	NM			r	~	V	V	,		V	V		GIND & CHASSAS TEST
-3-05	8:00	Win	V	V			V	~	V	V	1	1		SOUAE TEST
- 6-0T		NN			V	V	V	~			V	V		GND & CHASSIS
-6-05		NW	2	i			V	V	V	1	4	V		SOURCE
17-05		NOW			~	r	v	~			V	~		GNP & CHASSIS
7-05		4 pw	V	-		an est a constant	V	1	V	~	r	0		SOUPLE
											er vez-er			
						water at a								
			2 12 11 11 1											
			3											

Attachment of HRCR Items # 24 & # 25: Mate/Demate & Operation Logs (PWB S/N 039)

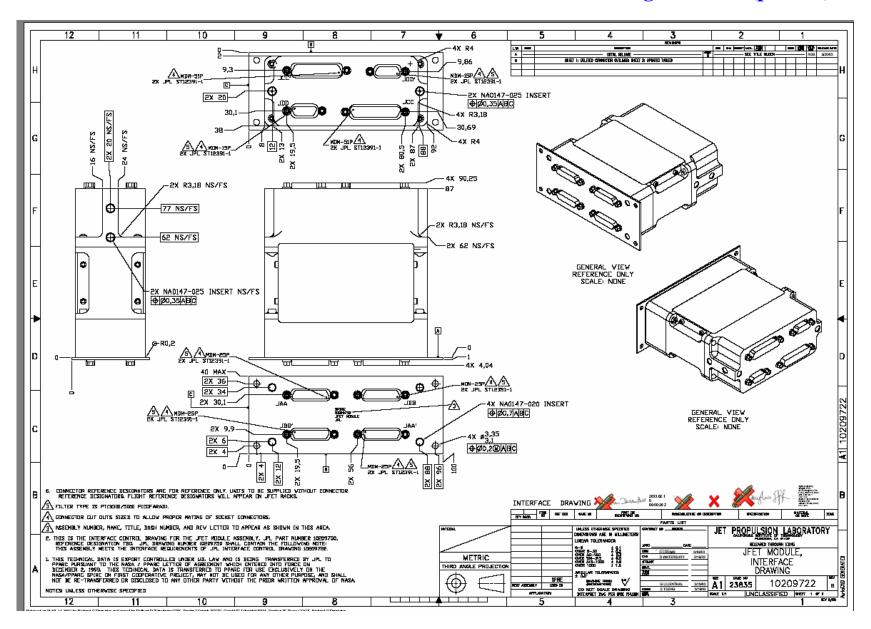
OPERATION LOG SHEET -- SPIRE JFET BOARDS MODULE

Mod. 13

DEVICE (BRD) S/N: 03 9 (53) PROJECT: SPIRE/JFET BOARD

DATE	TIME	TECH	PWR ON	PWR				DEMATE					NOTE	
27777127411				OFF	JAA	JBB	JCC	JDD	JAA	JBB	JCC	JDD	TRANSFORT	NOTE
	STOAM	ST.			V	V	V	V	-	-	- Marin	***		SMERON
123/04		NOV			-	****	-	(770)	-	,000	-	-		GND/CHASSY TEST
1/23/04		NIN	V	V		-	-	-	-	70	_	-		SOURCE TEST
11/04/04		NW			*****	1	-	-	-	dann	_	_		GND / CHISSY TEST
1/04/04		NM	V	i V	-		_	-	-		-	-		SOURCE TEST
1/11/04	9:45	NINGE			-	1	ir	V	or	v	0	i		REMOVE SAVER BOB.
1/11/04	10:00	NW			~	c	1	er			2	V		GND & CARSBY TEST
1/11/04		NW	V	i			V	V	V	V				SOURCE TEST
1/17/04	10:00	Nita			V	V	V	V			V	V		GND & CHARSOS TEST
117/04		NIM	V	V			V	L			V	-		SOURCE TEST
417/04		NAU			V	V	V	V			V	V		OND & CHASSUS TES,
117/04		www.	V	V			V	V	V	V	V	Ü		SOURCE TEST
16/05		NAM			1	V	V	2			V	w		GND & CHIKESS
16/05	3776-11	NAW	V	V			V	V	V	V	1	2		SOUPCE TEST
/7/05		NAW	117.0		V	V	V	~			~	0		GNP & CHASEIS
17/05		NAW	~	~			V	V	V	V	V	V		SOUPCE TEST
	,													
											V_1 =====			
								IV-						
											(20 <u>11</u>			
									_					

Attachment of HRCR Item # 26: MICD - JFET Interface Drawing 10209722 (p 1 of 2)



Attachment of HRCR Item # 26: MICD - JFET Interface Drawing 10209722 (p 2 of 2)

	12	11	10 9	8	7	*	6	5	4	3	- :	2 1
		JAA JEET DUTPUT 139	JAA' JEET OUTPUT 2A		JCC JFET INPUT 1			JUD JEET SERVICE 1	7 [JCC' JFET INPO	IT 9	1
	PIN #		PIN # PIN PURPUSE	PIN \$		1SE	PIN		\dashv \vdash		NE-LOZE	1
ΗΙ	1	SIGNAL M+	1 SIGNAL H+'	l	BIAS V+		1	Vss	1 I	1 BIAS V+'		i lı
11	2	SIGNAL N+	2 SIGNAL N+'	2	BIAS V-		2	V+	1 I	5 BIAS A-1		1
	3	SIGNAL P+	3 SIGNAL P+'	3	SIGNAL Y+		3	H+	7 I	3 SIGNAL Y+'		1
Ш	4	SIGNAL R+	4 SIGNAL R+'	4	SIGNAL W-		4	V-	7 I	4 SIGNAL V-'		1 F
	5	+2 JAMDIZ	5 SIGNAL S+'	5	SIGNAL V+		5	V-	7 I	5 SIGNAL V+'		1
	6	SIGNAL T+	6 SIGNAL T+'	6	SIGNAL T+		6	H+] [6 SIGNAL T+']
	7	SIGNAL U-	7 SIGNAL U-'	7	SIGNAL S-		7	V+] [7 SIGNAL S-]
G	8	SIGNAL V-	B SIGNAL V-	8	SIGNAL P+		8	Vss] [B SIGNAL P+'] [
	9	SIGNAL V-	9 SIGNAL W-	9	SIGNAL N-		9	BIAZ GND ZAIE	<u>ا</u> ا	9 SIGNAL N-/]
	10	SIGNAL X-	10 SIGNAL X-'	10	SIGNAL L-		10	Vald	⊣ ∣	10 SIGNAL L-/		
Н	l1	SIGNAL Y-	11 SIGNAL Y-'	11	SIGNAL K+		11	H-	-	11 SIGNAL K+'		l 1
	12	SIGNAL Z-	12 STGNAL Z-'	12	SIGNAL I-		12	CHASSIS GND	-	12 SIGNAL I-		- I
	13	FPU GND	14 SIGNAL H-'	13	SIGNAL H+			H-	⊣ ⊦	13 SIGNAL H+		- 1
	14	SIGNAL M-	15 SIGNAL N-'	14	SIGNAL F+			Auki EMD	- -	14 SIGNAL F+'		-l
F	15	SIGNAL P-	16 SIGNAL P-'	16	SIGNAL C+		13	THO GAN	┥ ├	16 SIGNAL C+*		
	17	SIGNAL R-	17 SIGNAL R-'	17	SIGNAL B-			JUDY JEET SERVICE 2		17 SIGNAL C+		
	18	SIGNAL S-	18 SIGNAL S-'	18	SIGNAL A-		PIN		7 H	18 SIGNAL A-		
Н	19	SIGNAL T-	19 SIGNAL T-'	19	BIAS GND		1	Vss'	7 H	19 BIAS GND'		1
	20	SIGNAL U+	20 SIGNAL U+'	20	SIGNAL Z+		2	V+'	7 H	20 SIGNAL Z+'		i 1
	21	SIGNAL V+	21 SIGNAL V+	21	SIGNAL X-		3	H+'	7 H	21 SIGNAL X-		i 1
_	22	SIGNAL W+	22 SIGNAL Y+	22	SIGNAL W+		4	V-] l	22 SIGNAL W+'		1 l.
E	23	SIGNAL X+	23 SIGNAL X+'	23	SIGNAL U-		5	V-] l	23 SIGNAL U-		†
	24	SIGNAL Y+	24 SIGNAL Y+'	24	SIGNAL T-		6	H+'	_	24 SIGNAL T-		1
		SIGNAL Z+	25 SIGNAL Z+'	25	SIGNAL R+		7	V+	_	25 SIGNAL R+'		1
▶				26	SIGNAL P-		8	Vss'	」 ∣	26 SIGNAL P-		1 +
		JES JEET DUTPUT 1A	JEST JEET DUTPUT 20	27	SIGNAL M+		9	YIND ZAIE	⊿ i	27 SIGNAL M+'		1
	PIN #		PIN # PIN PURPUSE	28	SIGNAL L+		10	Valdr	-l	28 SIGNAL L+']
_	1	SIGNAL A+	1 SIGNAL A+'	29	SIGNAL J-		11	H-'	-l	29 SIGNAL J-		1 l.
D	2	SIGNAL B+ SIGNAL C+	2 SIGNAL E+'	30	SIGNAL I+		12	CHASSIS GND	- ['+I JANDIZ DE]
	4	SIGNAL D+	4 SIGNAL II+1	31	SIGNAL G-		13		- [21 SIGNAL G-]
	5	SIGNAL E+	5 SIGNAL E+'	32	SIGNAL F-		14	Attenda and	-l	32 SIGNAL F-]
Н	6	SIGNAL F+	6 SIGNAL F+'	3:3	SIGNAL II+		15	TING CAD	_	33 SIGNAL II+] [
	7	SIGNAL G-	7 SIGNAL 5-1	34	SIGNAL C-					34 SIGNAL C-/]
	6	SIGNAL H-	B SIGNAL H-'	36	SIGNAL A+					35 SIGNAL A+		
_	9	SIGNAL I-	9 SIGNAL 1-'	36	SIGNAL Z-				- 1	36 SIGNAL Z-/		-
C	10	SIGNAL J-	10 SIGNAL J-'	37	SIGNAL Y-				-	37 SIGNAL Y-		
	l1	SIGNAL K-	11 SIGNAL K-'	36	SIGNAL X+				-	38 SIGNAL X+*		
	12	SIGNAL L-	12 SIGNAL L-'	39	SIGNAL V-				-	39 SIGNAL V-' 40 SIGNAL U+'		
Н	13	FPU GNO	13 FPU GND'	4D 41	SIGNAL U+				-	4D SIGNAL U+* 41 SIGNAL S+*		∤ F
	14	SIGNAL A-	14 SIGNAL A-'	42	SIGNAL R-				}	42 SIGNAL ST		
	15	SIGNAL B-	15 SIGNAL B-'	43	SIGNAL N+				}	43 SIGNAL N+		
ы	16	SIGNAL C-	16 SIGNAL C-'	44	SIGNAL M-				}	44 SIGNAL M-		- lı
1	17	SIGNAL D-	17 SIGNAL II-'	45	SIGNAL K-				}	45 SIGNAL K-		1
	18	SIGNAL E-	18 SIGNAL E-'	46	SIGNAL J+				}	46 SIGNAL J+		
	19	SIGNAL F-	19 SIGNAL F-'	47	SIGNAL H-				}	47 SIGNAL H-		†
Н	20	SIGNAL G+	20 SIGNAL G+'	49	SIGNAL G+				ŀ	4B SIGNAL G+		1 [
	21	SIGNAL H+	21 SIGNAL H+'	49	SIGNAL E+				ŀ	49 SIGNAL E+		1
	55	SIGNAL I+	22 SIGNAL 1+'	50	SIGNAL D-				ŀ	50 SIGNAL D-		1 I
A	53	SIGNAL J+	23 SIGNAL J+'	51	SIGNAL B+					51 SIGNAL B+		1 l
^		SIGNAL K+	24 SIGNAL K+'							-	TE PAR	· · · · · · · · · · · · · · · · · · ·
	25	SIGNAL L+	25 SIGNAL L+'								A1 238	
	12	11	10 9	8				5	_	3	FALL HOME	UNCLASSIFIED PETE FJ
	12	II II	iu 9	•		_) 3	4_	, J		1 - 1-

Attachment of HRCR Item #11:

SPIRE

Handling Document

Field Effect Transistor (JFET) Module

10209750-1

Prepared by: Kalyani Sukhatme

10 September, 2003

Hardware Handling Guidelines

Contamination: Open shipment suitcase in a FED-STD-209 Class 10,000 clean room (ISO 14644-1 class 7) or better. Handle hardware with gloves.

ESD: Handle with grounding straps, ESD-safe gloves and ESD smocks at an ESD-safe workstation. Maintain shorting plugs on the unit whenever ESD is a concern. Refer to attached electrical handling document for other important safety precautions.

Fragile: Do not drop or otherwise shock the hardware including the shipping suitcase and container.

Humidity Sensitive: Place hardware in a humidity controlled Class 10,000 clean room. Maintain humidity level at 35%-50% RH typical, for ESD safety.

SPIRE JFET Electrical Handling Document

1	Int	troduction	.1
	1.1	Hardware Description	.1
2	На	andling	.2
3	Po	ower ON Procedure	.2
4	Ele	ectrical Check-out Test: Characteristic Offset Voltage Measurement	.3

1. Introduction

This document provides guidelines for electrical handling for the SPIRE JFET Module.

1.1 Hardware Description

Each JFET module has two sets of 24 JFET channels. The JFET channels are populated on 1.0 micron thick Silicon Nitride membranes which provides thermal isolation. The operating temperature for these JFETs is ~120 K. The process of powering up the JFETs dissipates heat into the membrane resulting in a temperature increase with respect to the base temperature (4K to 10 K). Higher the power dissipation, higher is the temperature of the JFETs.

Each JFET channel consists of a matched pair of FETs (Figure 1.1-1) with a requirement for the offset voltage of less than **15 mV** between the matched pair. [The characteristic offset voltage is the difference between the source voltages $(V_{sa} \text{ and } V_{sb} \text{ with respect to ground})$ of the two FETs.]

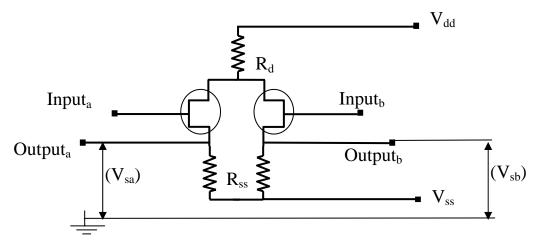


Figure 1.1-1

The Gates of the JFETs are the 'Inputs' of the circuit and the Sources (V_{sa} and V_{sb}) of the JFETs are the outputs, as marked in Figure 1.1-1. Vdd and Vss are the power lines for the circuit.

Handling

- 1. **The JFET Module is Contamination Sensitive**: Handle the unit with Gloves only in a FED-STD-209 Class 100000 clean room (ISO 14644-1 class 7) or better.
- 2. **The JFET Module is ESD Sensitive**: Please handle with appropriate ESD hardware handling procedures. Handle with grounding straps, ESD-safe gloves, ESD smocks at an ESD-safe workstation.
- 3. **The JFET Module is Fragile**: Please do not drop or otherwise shock the unit. Please DO NOT remove the cover of the JFET Module.

Power ON Procedure

1. The JFET Module should be powered on **WITH the shorting plugs** (JPL Supplied Protection connectors) in place and with the **inputs shorted to ground.** Pins #9 and #15 on the 15-pin MDM connectors on the JFET Module are the bias grounds on the module. These pins should also be shorted to the power supply ground. The unit may be powered up without the shorting plug only when the inputs are connected to the detector system.

Under no circumstances the unit should be powered up without the inputs shorted to ground either via the shorting plug (JPL Supplied) or via the detector system.

- 2. Do not exceed a voltage of +5 V for the Vdd line and -5 V for the Vss line of the JFET Module.
- 3. When removing the shorting plugs from the unit for installation into the instrument, please use standard ESD precautions including grounding straps, ESD-safe gloves, ESD smocks at an ESD-safe workstation.

Electrical Check-out Test: Characteristic Offset Voltage Measurement

- 1) Verify that the gates of the JFET channels (Inputs) are shorted together and grounded.
- 2) Apply the power supply ground to the bias ground pins on the unit (Pins 9 and 15 on the 15-pin MDM connectors)
- 3) Power on the JFET modules with Vdd = +3 V and Vss = -1.5 V
- 4) Verify that the handheld multimeter is in calibration.
- 5) Connect one side of the handheld multimeter to ground (Power supply ground).
- 6) And measure the voltage with respect to ground of each side (V_{sa} and V_{sb}) of each channel.
- 7) Calculate the characteristic offset voltage (V_{offset}) for each channel ($V_{offset} = V_{sa} V_{sb}$)
- 8) Compare the values for each of the channels with the specific datasheet provided with the unit. The datasheets accompanying the unit also provides the values for the drain and source currents for a similar test performed at JPL.

REFER TO MEASURED SOURCE VOLTAGE DATA FOR ACTUAL HARDWARE. Here is an example of the source voltage values and the drain and the source currents obtained for such a test at room temperature are given in the Table 4-1

T, JFET	rm T						
Vdd	3 V						
Vss	-1.5 V						
ldd	1.564 mA						
lss	1.5686 mA						
Channel #	(V)	DELTA (V)					
1	1.130	0					
1	1.130	U					
2	1.075	0.001					
2	1.074	0.001					
2	0.781	0.001					
3	0.780	0.001					
4	1.088	0.005					
4	1.093	0.005					
5	0.834	0.001					
3	0.833	0.001					
6	1.012	0.003					
0	1.015	0.003					
7	0.785	0.002					
/	0.787	0.002					
8	1.148	0.004					
0	1.144	0.004					
9	0.753	0					
9	0.753	U					

_	_					
10	0.693	0.008				
	0.701	0.000				
11	1.110	0.004				
11	1.114	0.004				
12	0.758	0.001				
12	0.759	0.001				
13	0.832	0.002				
- 10	0.830	0.002				
14	1.264	0.001				
1.	1.265	0.001				
15	1.206	0				
	1.206					
16	0.818	0.001				
	0.819	0.001				
17	0.526	0.005				
	0.521	0.000				
18	1.423	0				
	1.423					
19	0.773	0.002				
	0.775	0.002				
20	0.873	0.004				
-	0.877					
21	1.387	0.006				
	1.393					
22	1.417	0.003				
	1.420					
23	0.887	0.002				
	0.889					
24	0.888	0.003				
	0.891					

- END OF Attachment of HRCR Item # 11: JFET Module Handling Document

END OF HRCR PACKAGE